

## Refine Search

### Search Results -

Terms	Documents
6121164	8

Database:

US Pre-Grant Publication Full-Text Database  
 US Patents Full-Text Database  
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 EPO Abstracts Database  
 JPO Abstracts Database  
 Derwent World Patents Index  
 IBM Technical Disclosure Bulletins

Search:

L19





### Search History

DATE: Monday, June 27, 2005    [Printable Copy](#)    [Create Case](#)

<u>Set</u> <u>Name</u>	<u>Query</u>	<u>Hit</u> <u>Count</u>	<u>Set</u> <u>Name</u> result set
<i>DB=USPT; PLUR=YES; OP=OR</i>			
<u>L19</u>	6121164	8	<u>L19</u>
<u>L18</u>	612164	9	<u>L18</u>
<u>L17</u>	6103601	27	<u>L17</u>
<u>L16</u>	61036018	0	<u>L16</u>
<u>L15</u>	6008120	36	<u>L15</u>
<u>L14</u>	112 and "single damascene"	1	<u>L14</u>
<u>L13</u>	112 and "atomic percent fluorine"	0	<u>L13</u>
<u>L12</u>	L11 and (("via hole") or (trench))	14	<u>L12</u>
<u>L11</u>	l8 and L10	22	<u>L11</u>
<u>L10</u>	usg near4 fsg	86	<u>L10</u>
<u>L9</u>	usg near4 fsgL8	0	<u>L9</u>
<u>L8</u>	fsg NEAR5 SUBSTRATE	102	<u>L8</u>
<u>L7</u>	usg	1239	<u>L7</u>

<u>L6</u>	6861701	1	<u>L6</u>
<u>L5</u>	L3 and ("trench gate" near7 (silicon near3 metal near5 (silicon or silicide)))	3	<u>L5</u>
<u>L4</u>	L3 and "trench gate"	945	<u>L4</u>
<u>L3</u>	power MOSFET	1110305	<u>L3</u>
<i>DB=USOC; PLUR=YES; OP=OR</i>			
<u>L2</u>	L1	0	<u>L2</u>
<i>DB=PGPB; PLUR=YES; OP=OR</i>			
<u>L1</u>	2003/0178673	0	<u>L1</u>

END OF SEARCH HISTORY